


# PRODUCT SPECIFICATION

DATE:08/25/2006

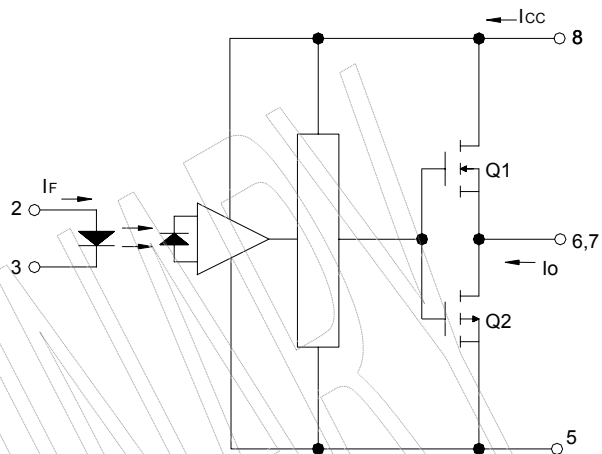
	Photocoupler: <h2>KTLP350</h2>	No.60P32002	Preliminary
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## ※THE KTLP250 BUILT- IN DIRECT DRIVE CIRCUIT FOR GATE DRIVING CIRCUIT OF IGBT OR POWER MOSFET.

### • Feature:

- 1.This unit is 8.lead DIP package.
- 2.Input threshold current:  $I_F=5\text{mA}(\text{max.})$
- 3.Supply current ( $I_{CC}$ ):  $2\text{mA}(\text{max.})$
- 4.Supply voltage ( $V_{CC}$ ): 10 – 30V
- 5.Output current ( $I_O$ ):  $\pm 2.5\text{A}(\text{max.})$
- 6.Switching time ( $t_{pLH}/t_{pHL}$ ):  $0.5\mu\text{s}(\text{max.})$
- 7.Isolation voltage:  $3750\text{Vrms}(\text{min.})$

### ■ Functional Diagram



### • Applications:

- 1.Transistor Inverter
- 2.Inverter For Air Conditionor
- 3.IGBT Gate Drive
- 4.Power MOS FET Gate Drive
- 5.IH(Induction Heating)

### ■ Truth Table

LED	OUTPUT	Q1	Q2
ON	HIGH LEVEL	ON	OFF
OFF	LOW LEVEL	OFF	ON

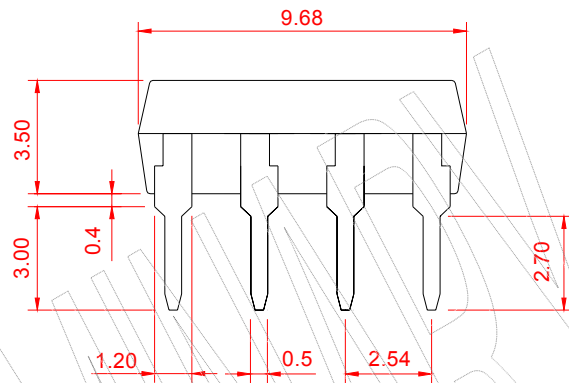
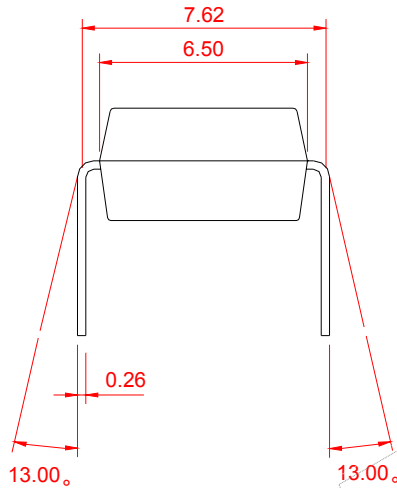
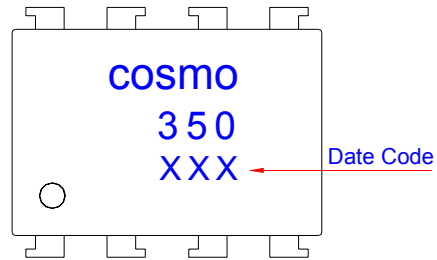
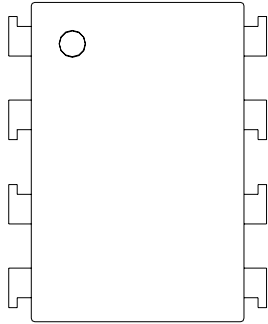
\* The use of a  $0.1\mu\text{F}$  bypass capacitor must be connected between pins 8 and 5 is recommended.

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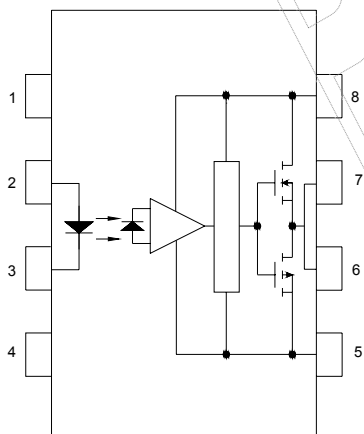
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## 1. Output Dimensions : Unit (mm)



TOLERANCE :  $\pm 0.2$  mm

## 2. KTLP350 Top View:



Pin 1:	N.C.
Pin 2:	Anode
Pin 3:	Cathode
Pin 4:	N.C.
Pin 5:	GND
Pin 6:	Vo (Voltage Output)
Pin 7:	Vo (Voltage Output)
Pin 8:	Vcc

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### ■ Absolute Maximum Ratings (Ta = 25°C)

Parameter		Symbol	Rating	Unit	
Input	Forward Current	$I_F$	20	mA	
	Forward Current Derating(Ta $\geq$ 70°C)	$\Delta I_F / \Delta T_a$	-0.54	mA / °C	
	Peak Transient Forward Current (*Note 1)	$I_{FPT}$	1	A	
	Reverse Voltage	$V_R$	5	V	
	Junction Temperature	$T_j$	125	°C	
Output	"H"Peak Output Current(Pw $\leq$ 2.5 $\mu$ s,f $\leq$ 15kHz) (*Note 2)		$I_{OPH}$	$\leq$ 2.5	A
	"L"Peak Output Current(Pw $\leq$ 2.5 $\mu$ s,f $\leq$ 15kHz) (*Note 2)		$I_{OPL}$	+2.5	A
	Output Voltage	(Ta < 95°C)	$V_O$	35	V
	Supply Voltage	(Ta < 95°C)	$V_{CC}$	35	V
	Output Voltage Derating (Ta $\geq$ 95°C)		$\Delta V_O / \Delta T_a$	-1.0	V / °C
	Supply Voltage Derating(Ta $\geq$ 95°C)		$\Delta V_{CC} / \Delta T_a$	-1.0	V / °C
	Junction Temperature		$T_j$	125	°C
Operating Frequency (*Note 3)		f	50	KhZ	
Operating Temperature Range		$T_{opr}$	-40~100	°C	
Storage Temperature Range		$T_{stg}$	-55~125	°C	
Lead Soldering Temperature(10s) (*Note 4)		$T_{sol}$	260	°C	
Isolation Voltage (AC,1min.,R.H $\leq$ 60%) (*Note 5)		BVs	3750	Vrms	

\*Note1:Pulse width Pw  $\leq$  1 $\mu$ s,300pps.

\*Note2:Exponential waveform pulse width Pw $\leq$ 0.3 $\mu$ s,f $\leq$ 15kHz.

\*Note3:Exponential waveform, $I_{OPH} \geq -2.0A (\leq 0.3\mu s)$ , $I_{OPL} \leq +2.0A (\leq 0.3\mu s)$ .

\*Note4:It IS 2 mm or more from a lead root.

\*Note5:Device considered a two terminal device: Pin1,2,3 and 4 shorted together,  
and pins 5,6,7 and 8 shorted together.

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### Electrical Characteristics (Ta = -40~100°C, unless otherwise specified)

Parameter	Symbol	Test Circuit	Test Condition	Min.	Typ.	Max.	Unit	
Input forward voltage	$V_F$	—	IF=10mA, Ta=25°C	—	1.6	1.8	V	
Temperature coefficient of forward voltage	$\Delta V_F / \Delta Ta$	—	IF=10mA	—	-2.0	—	mV/°C	
Input reverse current	$I_R$	—	VR=5V, Ta=25°C	—	—	10	μA	
Input capacitance	$C_T$	—	V=0, f=1MHz, Ta=25°C	—	45	250	pF	
Output current (*A)	“H” level	$I_{OPH}$	3	VCC=30V IF=5mA Vb=-3.5V	—	-1.6	-1.0	A
				VCC=15V IF=5mA Vb=-7.0V	—	—	-2.0	
	“L” level	$I_{OPL}$	2	VCC=30V IF=0mA Va=2.5V	1.0	1.6	—	
				VCC=15V IF=0mA Vb=7.0V	2.0	—	—	
Output voltage	“H” level	$V_{OH}$	4	VCC1=15V, VEE1=-15V RL=200Ω, IF=5mA	11	13.7	—	V
	“L” level	$V_{OL}$	5	VCC1=15V, VEE1=-15V RL=200Ω, VF=0.8V	—	-14.9	-12.5	
Supply current	“H” level	$I_{CCH}$	—	VCC=30V, IF=10mA, Ta=25°C	—	1.3	2.0	mA
	“L” level	$I_{CCL}$	—	VCC=30V, IF=0mA, Ta=25°C	—	1.3	2.0	
Threshold input current	“Output L→H”	$I_{FLH}$	—	VCC=15V, Vo>1V, Io=0mA	—	1.8	5	mA
Threshold input voltage	“Output H→L”	$V_{FHL}$	—	VCC=15V, Vo>1V, Io=0mA	0.8	—	—	V
Supply voltage	$V_{CC}$	—	—	10	—	30	V	
Capacitance (input-output)	$C_S$	—	Vs=0, f=1MHz, Ta=25°C	—	1.0	2.0	pF	
Resistance (input-output)	$R_S$	—	Vs=500V, Ta=25°C, R.H. ≤60%	$1 \times 10^{12}$	$10^{14}$	—	Ω	

\* All typical values are at Ta=25°C (\*A):Duration of Io time ≤ 50μs(1 Pulse)

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### ■ Switching Characteristics (Ta = -20~70°C, unless otherwise specified)

Parameter	Symbol	Test Circuit	Test Condition	Min.	Typ.	Max.	Unit
Propagation delay time	"L→H"	$t_{pLH}$	IF=5mA (Note8) VCC1=+15V, VEE1=-15V RL=20Ω	50	260	500	μs
	"H→L"	$t_{pHL}$		50	260	500	
Output rise time	$t_r$	6		—	15	—	
Output fall time	$t_f$			—	8	—	
Common mode transient immunity at high level output	$C_{MH}$	7	$V_{CM}=600V, I_F=8mA$ $V_{CC}=30V, Ta=25°C$	-5	—	—	KV / μs
Common mode transient immunity at low level output	$C_{ML}$	7	$V_{CM}=600V, I_F=0$ $V_{CC}=30V, Ta=25°C$	5	—	—	KV / μs

\* All typical values are at Ta=25°C.

\*Note 8: Input signal rise time (fall time) < 0.5μs.

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■ Test Circuit:

Fig.1 : Top View

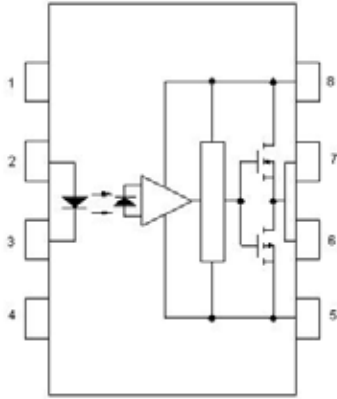


Fig.2 :  $I_{OPL}$  Measure.

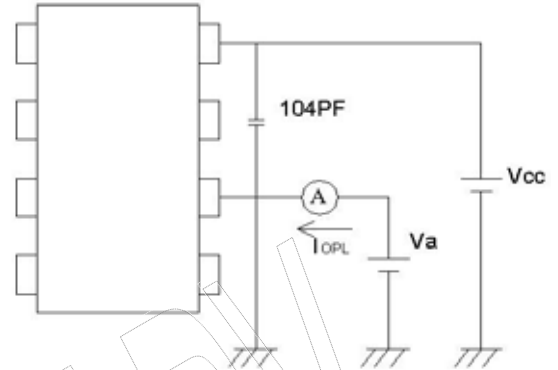


Fig.3 :  $I_{OPH}$  Measure.

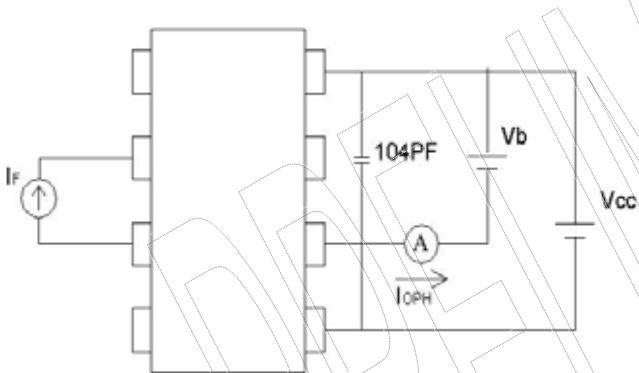


Fig.4 :  $V_{OH}$  Measure.

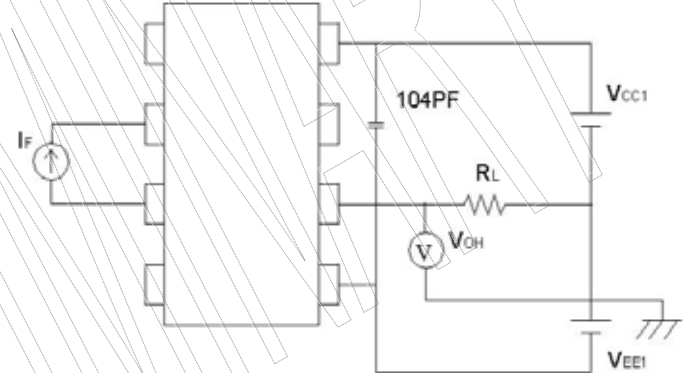
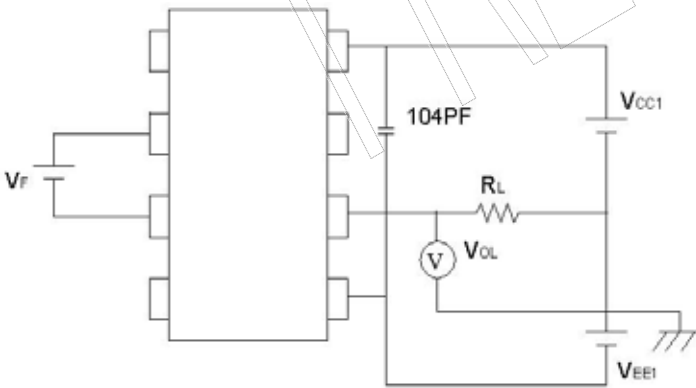


Fig.5 :  $V_{OL}$  Measure.



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Fig.6:  $t_{pLH}$ ,  $t_{pHL}$ ,  $t_r$ ,  $t_f$  Measure.

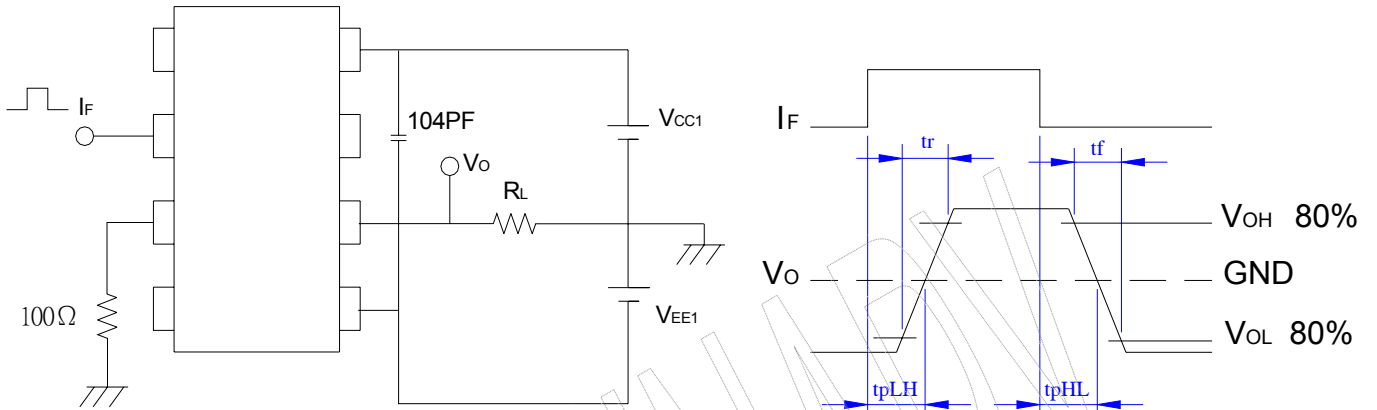
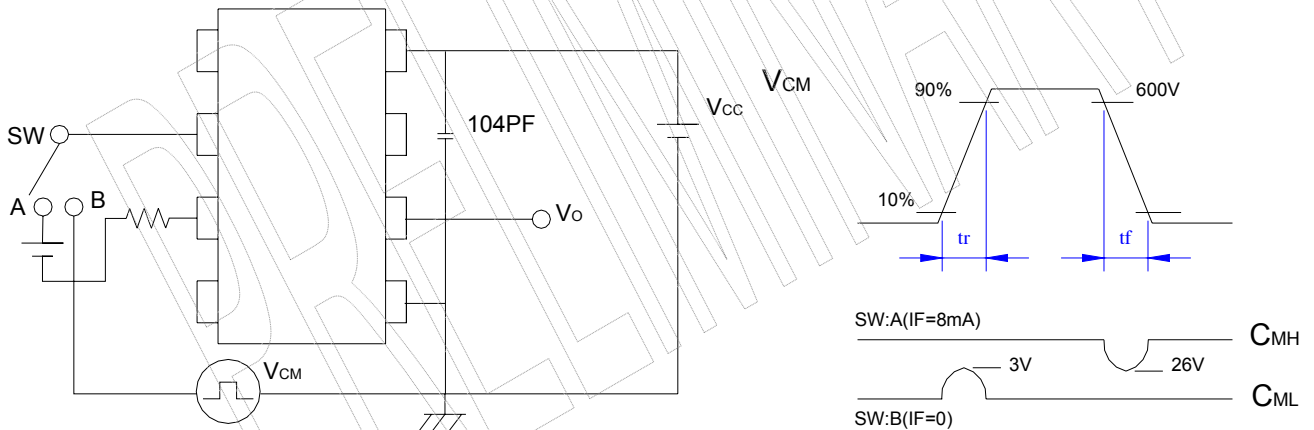


Fig.7:  $C_{MH}$ ,  $C_{ML}$ .



$$C_{ML} = \frac{480(V)}{t_r (\mu s)} \quad ; \quad C_{MH} = \frac{480(V)}{t_f (\mu s)}$$

\* $C_{ML}$ ( $C_{MH}$ ) is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the low (high) state.

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